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Electronic Filing System (EFS) Data
Electronic Patent Application Submission
USPTO Use Only

EFS ID: 76168
Application ID: 09941827
Title of Invention: Method of Improved High K
Dielectric-Polysilicon Interface
for CMOS Devices
First Named Inventor: Ronald Weimer
Domestic/Foreign Application: Domestic Application
Filing Date: 2001-08-29
Effective Receipt Date: 2005-01-18
Submission Type: Information Disclosure
Statement
Filing Type:
Confirmation number: 7551
Attorney Docket Number: MTI-31532




Total Fees Authorized: 180.0
Payment Category: Deposit Account
Deposit Account Number: 232053
Deposit Account Name: Kristine M. Strodthoff
Access Code: ****
RAM Payment Status: RAM success
RAM User ID: EFSPROD
RAM Accounting Date: 2005-01-18
RAM Sequence Number: 91

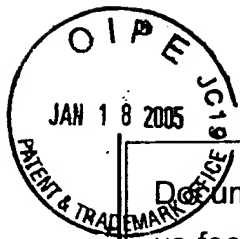
Digital Certificate Holder: cn=Kristine M. Strodthoff,ou=Registered Attorneys,ou=Patent and
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**TRANSMITTAL**

Electronic Version v1.1

Stylesheet Version v1.1.0

Title of Invention	Method of Improved High K Dielectric-Polysilicon Interface for CMOS Devices							
Application Number: 09/941827 								
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<table border="1"><tr><td>Submitted by:</td><td>Elec. Sign.</td><td>Sign. Capacity</td></tr><tr><td>Kristine M. Strodthoff Registered Number: 34259</td><td>/kms/</td><td>Attorney</td></tr></table>			Submitted by:	Elec. Sign.	Sign. Capacity	Kristine M. Strodthoff Registered Number: 34259	/kms/	Attorney
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Kristine M. Strodthoff Registered Number: 34259	/kms/	Attorney						



Documents being submitted

us-fee-sheet

us-ids

Files

MTI-31532-usfees.xml

us-fee-sheet.xml

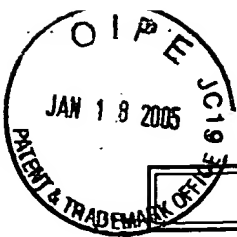
us-fee-sheet.dtd

MTI-31532-usidst.xml

us-ids.dtd

us-ids.xml

Comments

**FEE TRANSMITTAL**

Electronic Version v10
Stylesheet Version v10


Title of Invention	Method of Improved High K Dielectric-Polysilicon Interface for CMOS Devices										
Application Number: 09/941827 											
Date: 2001-08-29											
First Named Applicant: Ronald A. Weimer											
Attorney Docket Number: MTI-31532											
Art Unit: 2813											
Examiner: Yennhu B. Huynh											
TOTAL FEE AUTHORIZED \$180											
Patent fees are subject to annual revisions on or about October 1st of each year.											
<table border="1"><thead><tr><th>Fee Description</th><th>Fee Code</th><th>Amount \$</th><th>Fee Paid \$</th></tr></thead><tbody><tr><td>Submission Of Information Disclosure Stmt Fee</td><td>1806</td><td>180</td><td>180</td></tr></tbody></table>				Fee Description	Fee Code	Amount \$	Fee Paid \$	Submission Of Information Disclosure Stmt Fee	1806	180	180
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Submission Of Information Disclosure Stmt Fee	1806	180	180								
AUTHORIZED BILLING INFORMATION The commissioner is hereby authorized to charge indicated fees and credit any overpayments to: Deposit account number: 232053 Access Code ***** Deposit name: Whyte Hirschboeck Dudek S.C. Deposit authorized name: Kristine M. Strodthoff Signature: /kms/ Date (YYYYMMDD): 2005-01-18											



ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention	Method of Improved High K Dielectric-Polysilicon Interface for CMOS Devices																																				
<p>Application Number: 09/941827 </p> <p>Confirmation Number: 7551</p> <p>First Named Applicant: Ronald Weimer</p> <p>Attorney Docket Number: MTI-31532</p> <p>Art Unit: 2813</p> <p>Examiner: Yennhu B. Huynh</p> <p>Search string: (6548368 or 6278166 or 6063698).pn.</p> <p>US Patent Documents</p> <p>Note: Applicant is not required to submit a paper copy of cited US Patent Documents :</p> <table border="1"><thead><tr><th>init</th><th>Cite.No.</th><th>Patent No.</th><th>Date</th><th>Patentee</th><th>Kind</th><th>Class</th><th>Subclass</th></tr></thead><tbody><tr><td></td><td>1</td><td>6548368</td><td>2003-04-15</td><td>Narwankar et al.</td><td>B1</td><td>438</td><td>398</td></tr><tr><td></td><td>2</td><td>6278166</td><td>2001-08-21</td><td>Ogle, Jr.</td><td>B1</td><td>257</td><td>411</td></tr><tr><td></td><td>3</td><td>6063698</td><td>2000-05-16</td><td>Tseng et al.</td><td></td><td>438</td><td>585</td></tr></tbody></table> <p>Signature</p> <table border="1"><thead><tr><th>Examiner Name</th><th>Date</th></tr></thead><tbody><tr><td></td><td></td></tr></tbody></table>		init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass		1	6548368	2003-04-15	Narwankar et al.	B1	438	398		2	6278166	2001-08-21	Ogle, Jr.	B1	257	411		3	6063698	2000-05-16	Tseng et al.		438	585	Examiner Name	Date		
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